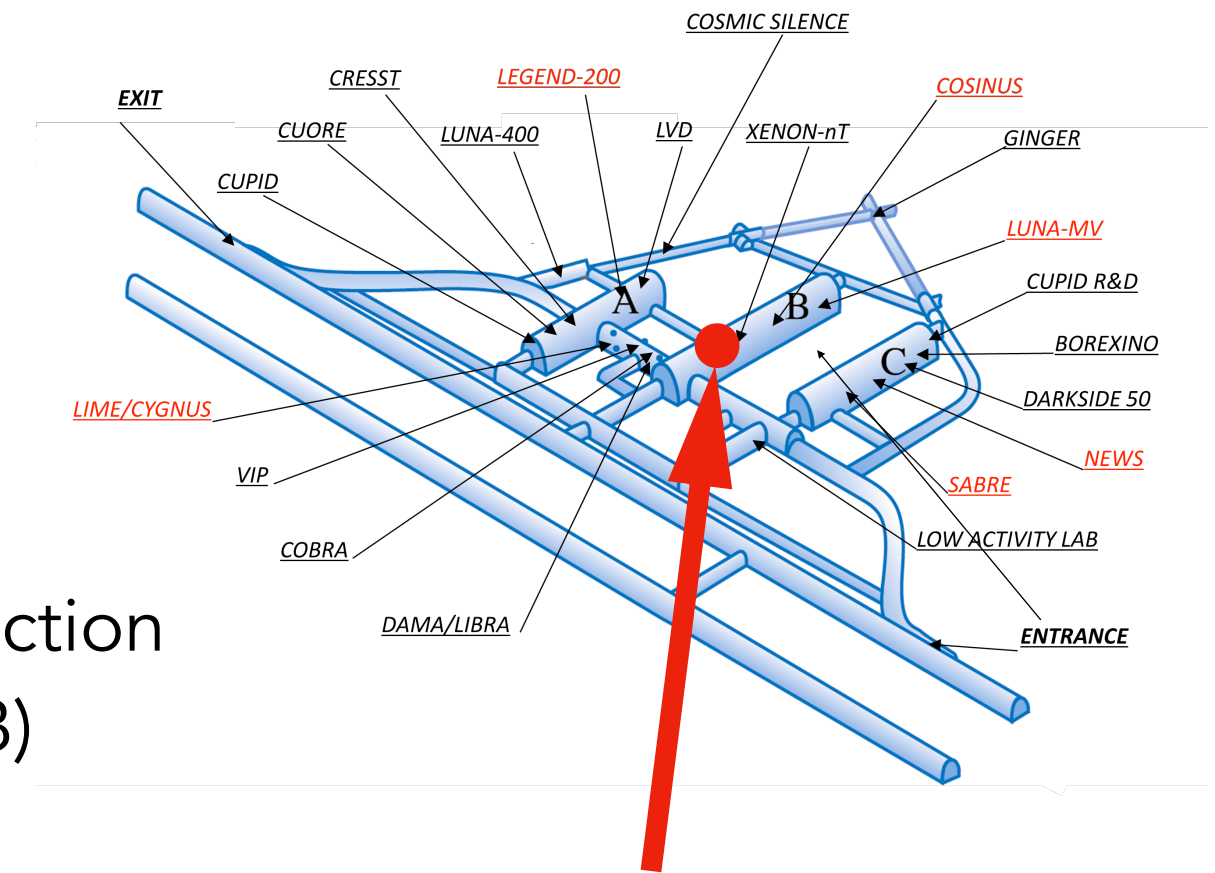


Status at LNGS

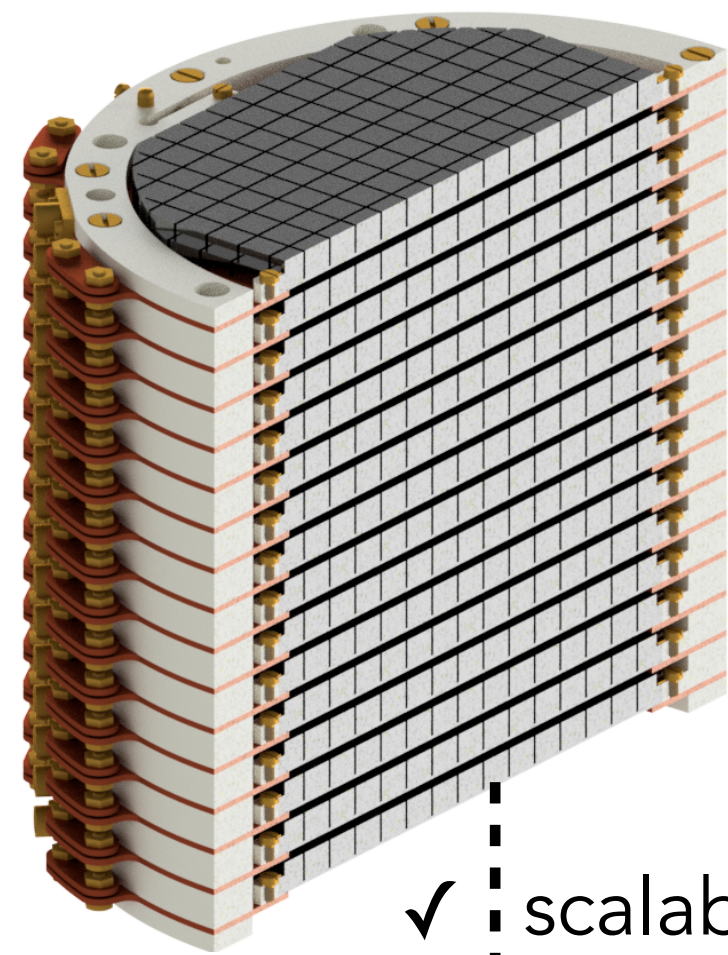
Antonio D'Addabbo (LNGS INFN)
Bimonthly digest, 27 March 2025



Overview



ProteoxMX dilution cryostat by Oxford Instruments



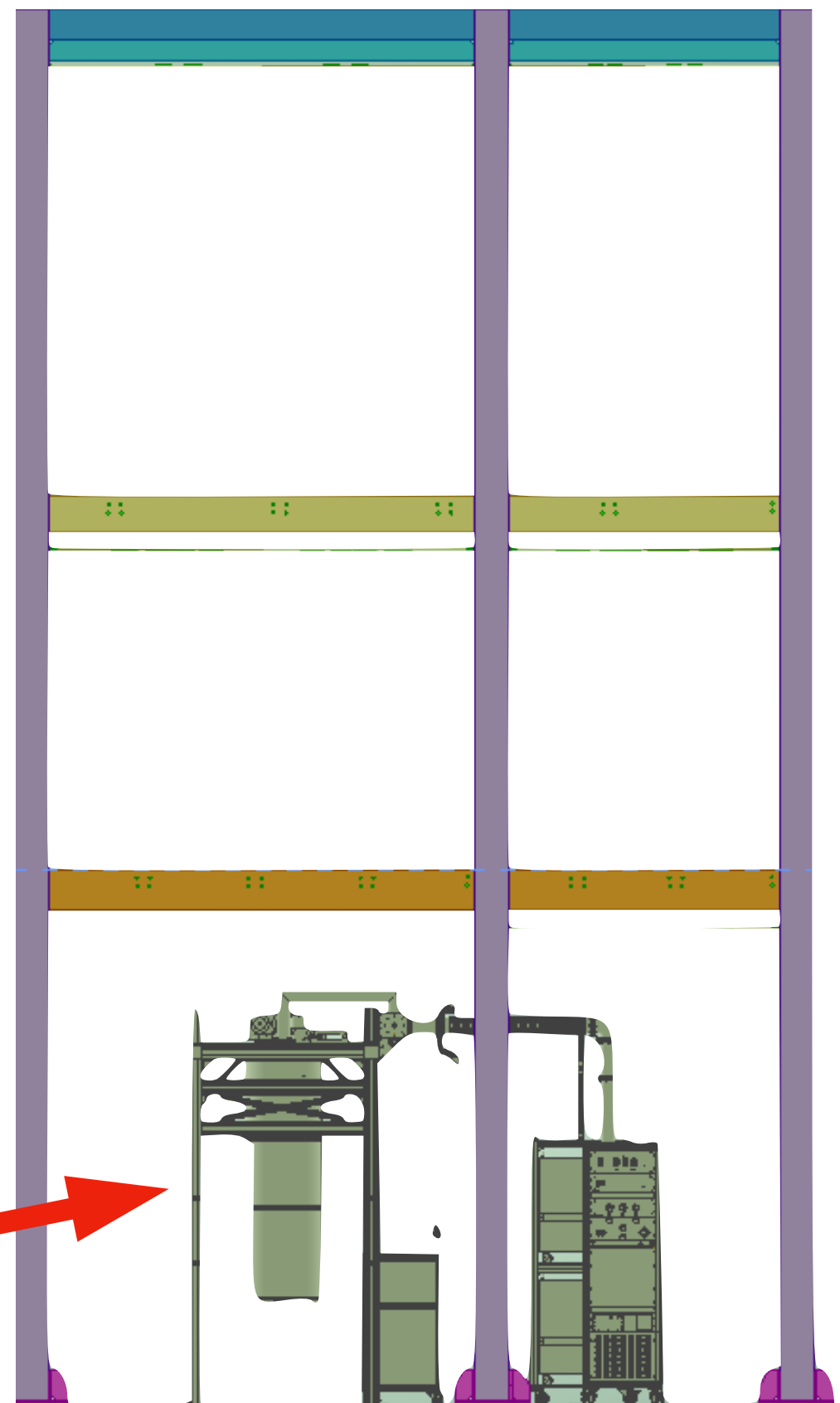
Detector

- ✓ 800 g of silicon target
- ✓ 2300 detector units (dice)
- ✓ No inert material in detector vol
- ✓ fully active
- ✓ fiducialization (600 g)



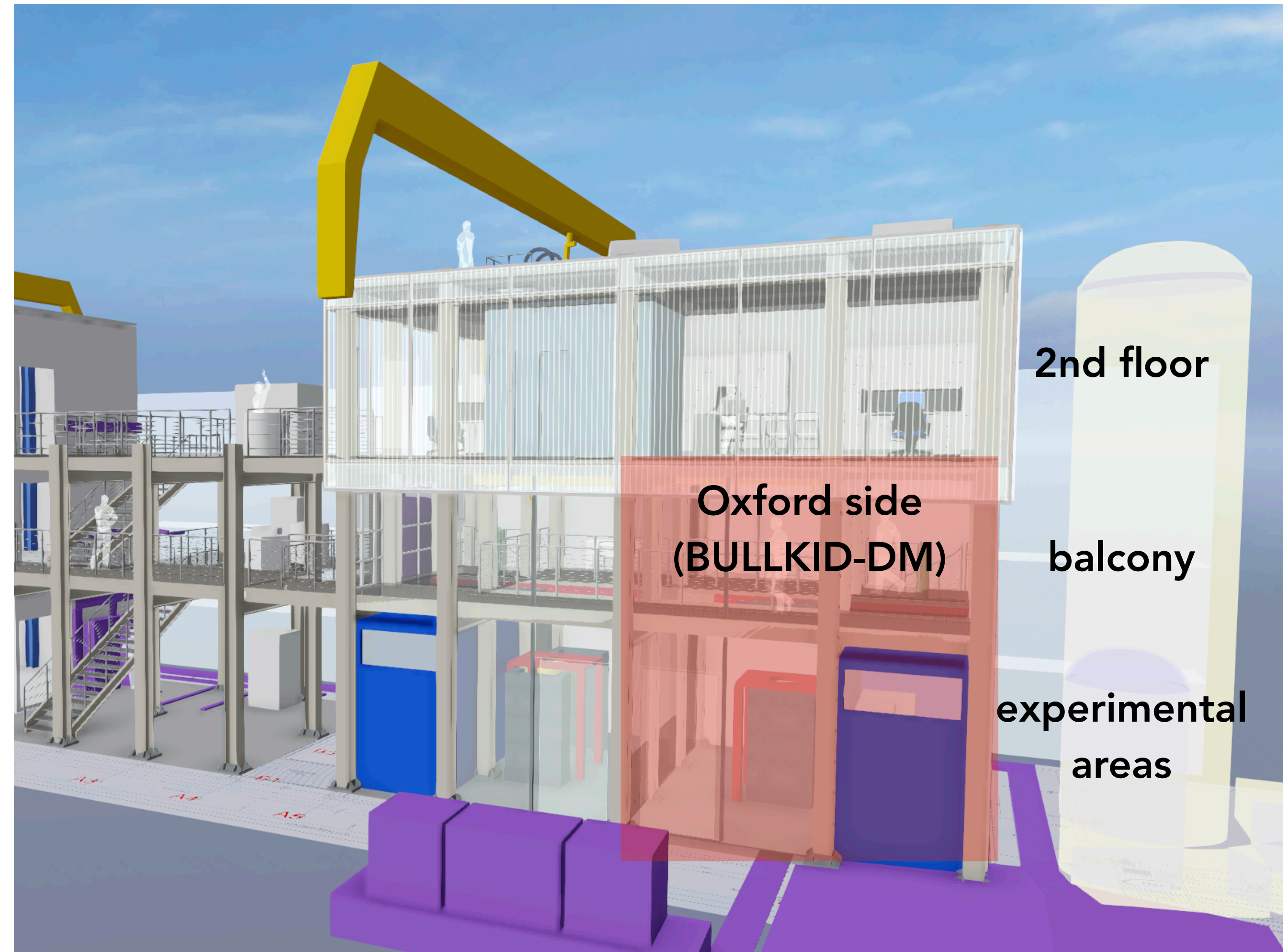
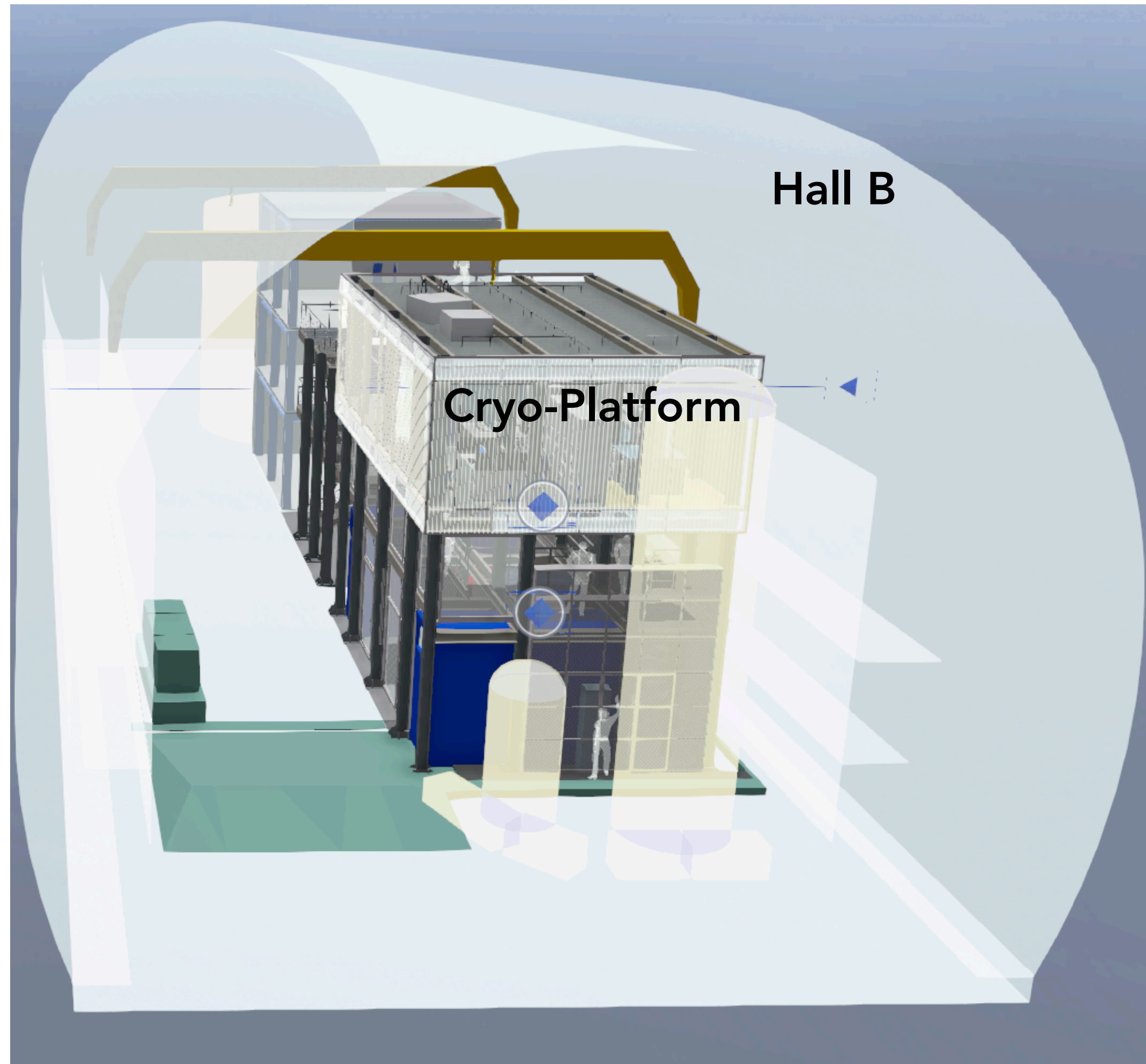
Delivery and commissioning in June 2025

Cryo-Platform facility under construction in the LNGS underground (Hall-B)



Ready by fall 2025

Cryo-Platform



Cryo-P area: late 2024

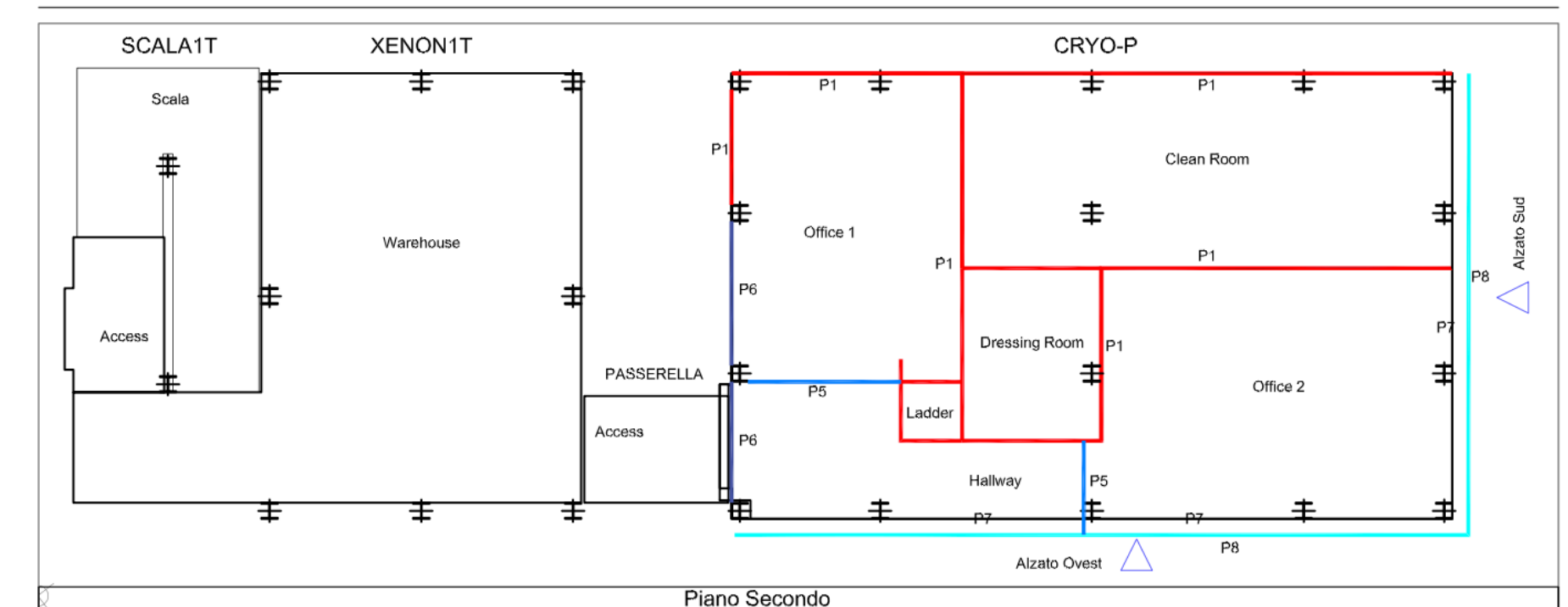
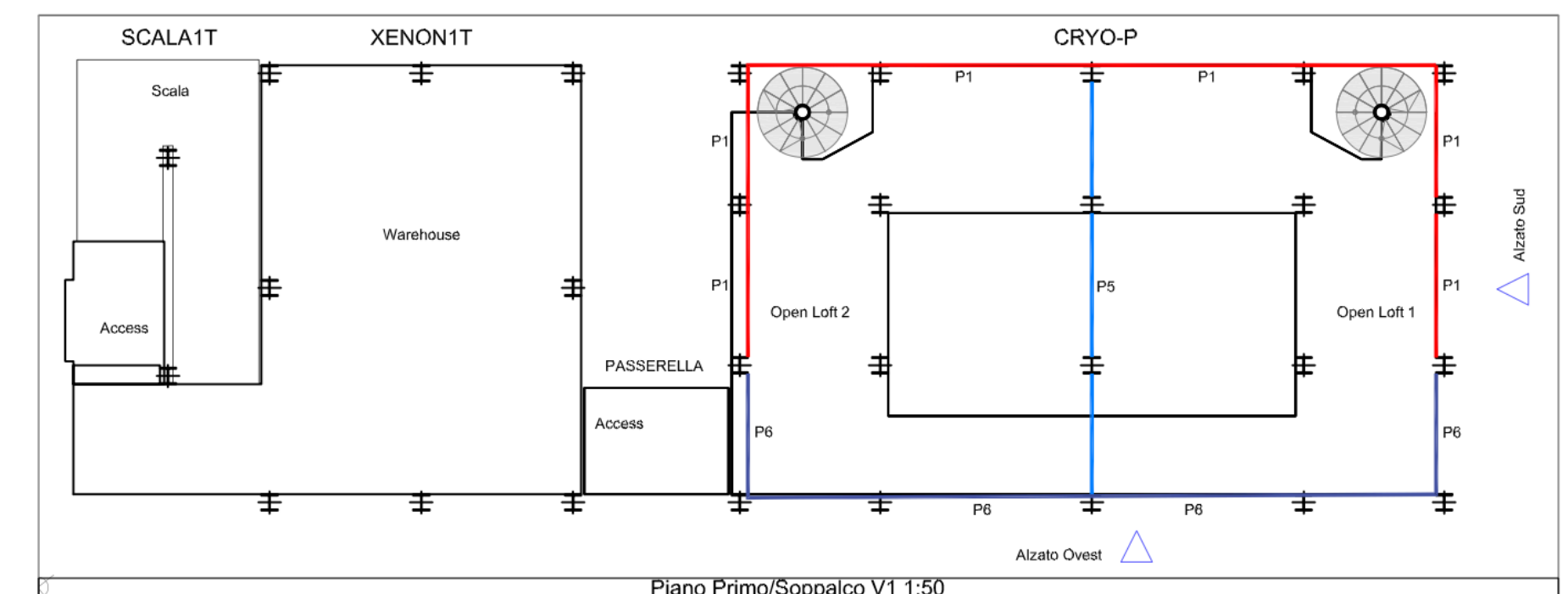
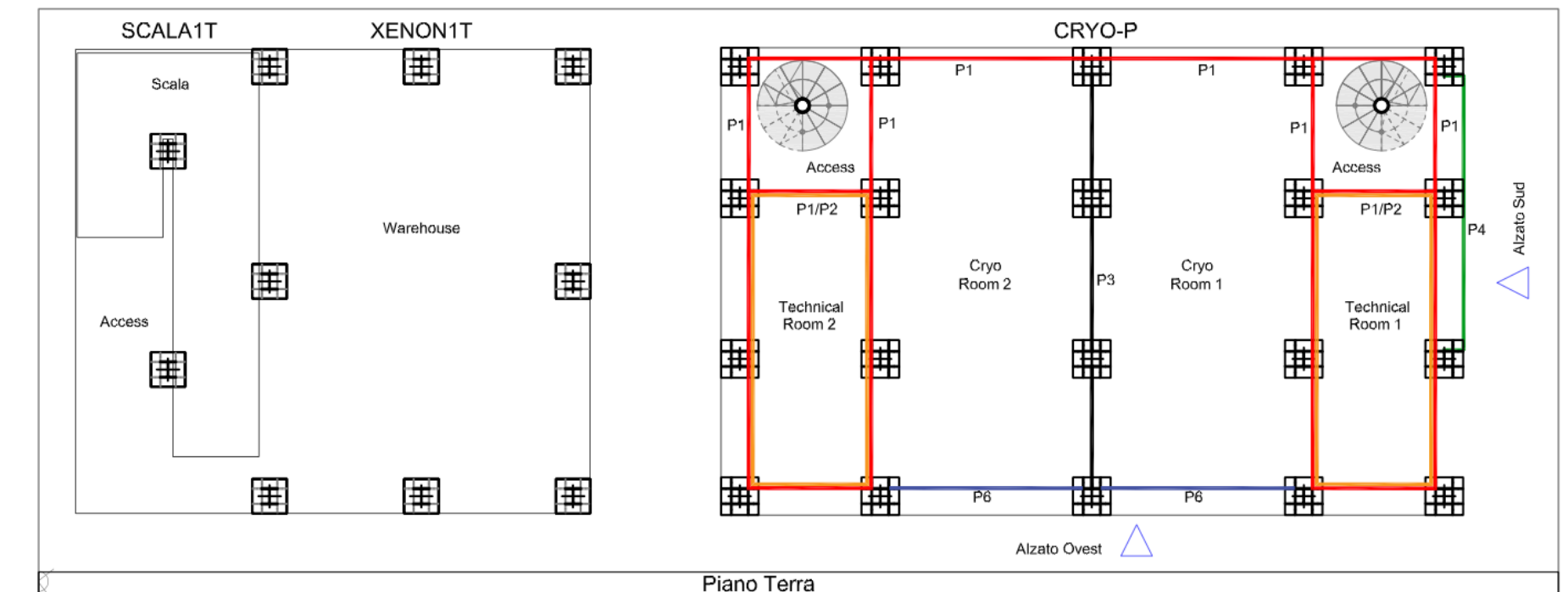
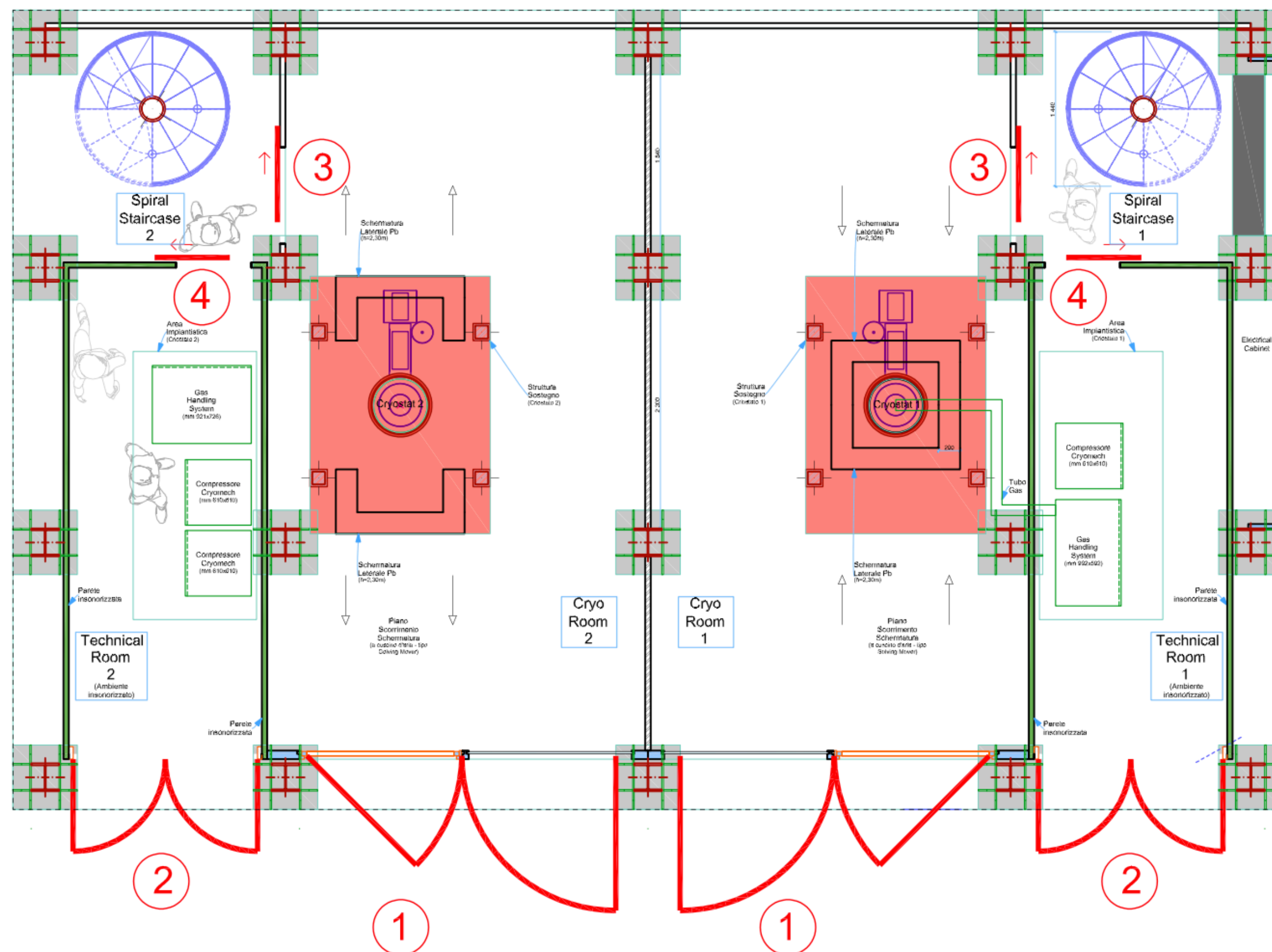


Cryo-P area: early 2025



Cryo-P utilities

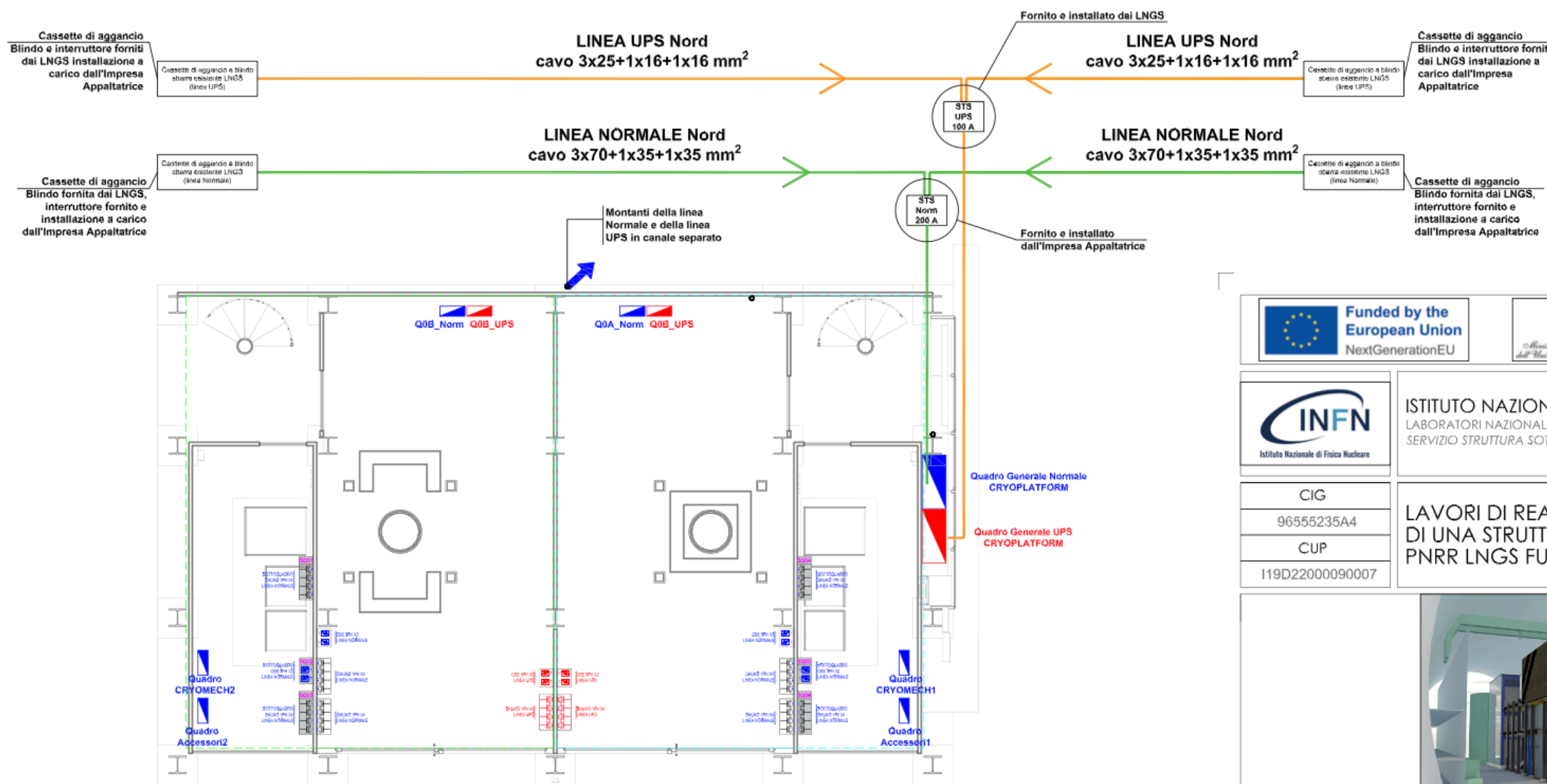
- Definition of infill walls, partitions and ceilings
- Definition of fixtures and lighting



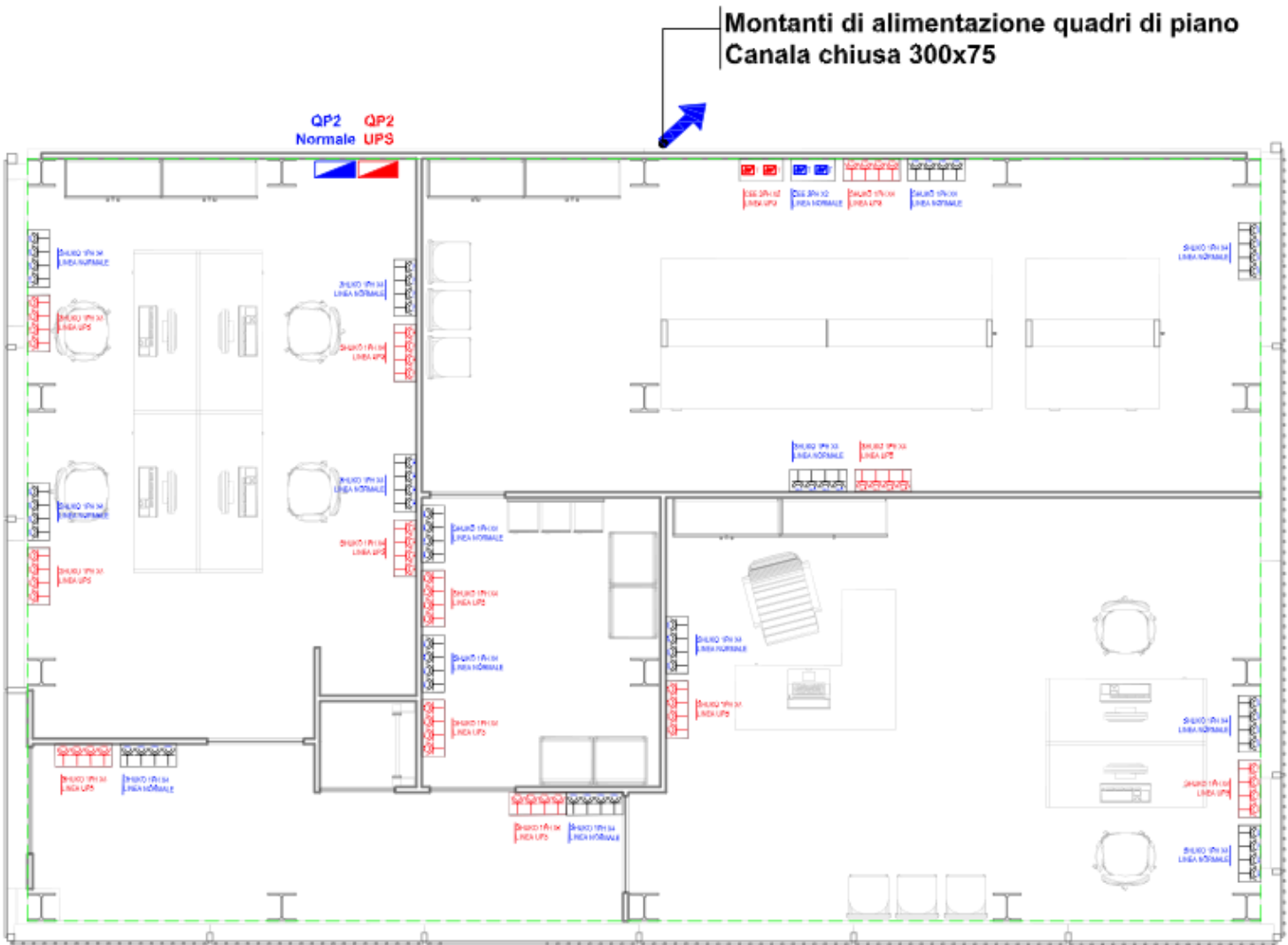
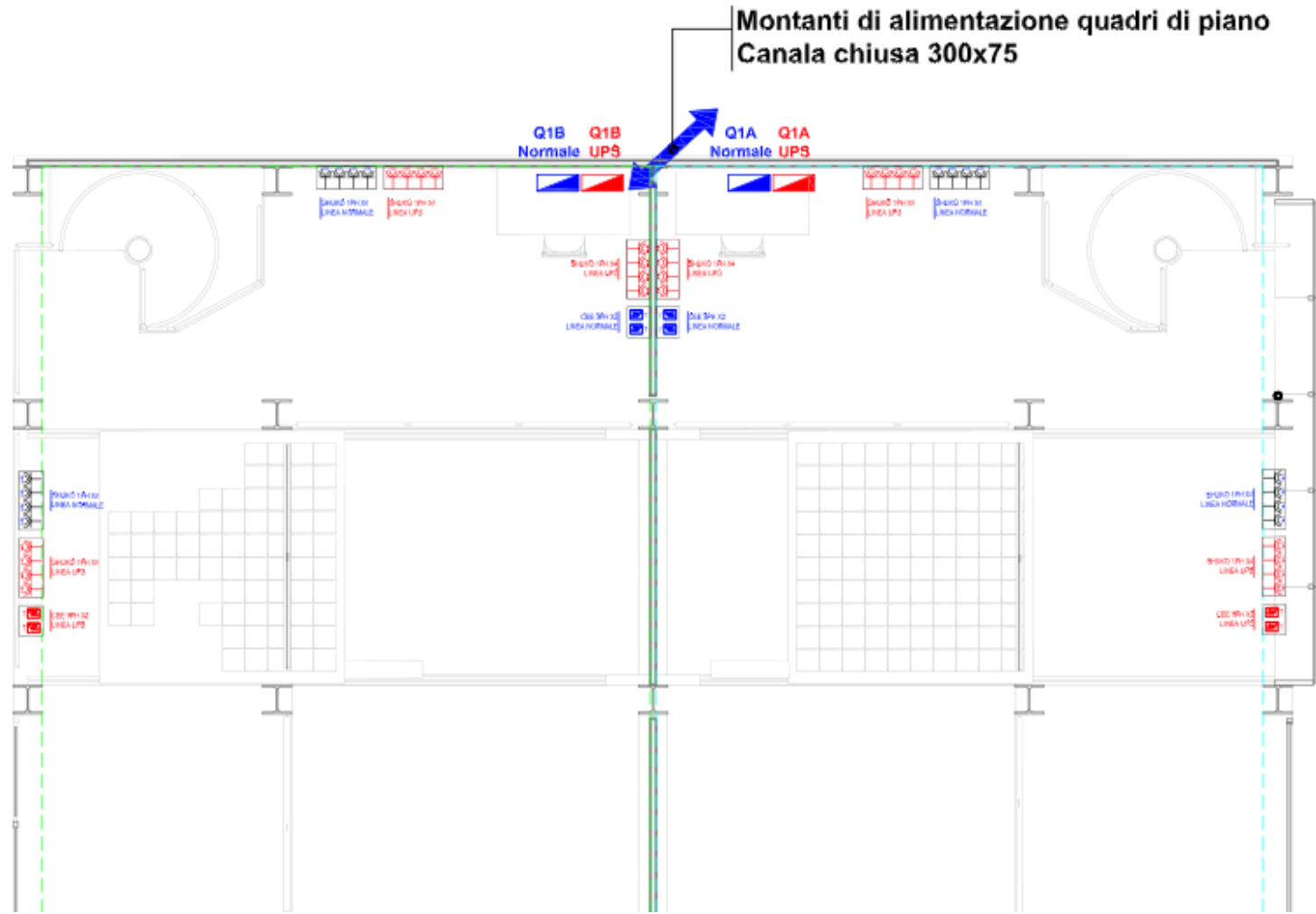
Cryo-P utilities: electrical and network

RETE ELETTRICA - Piano Terra

Scala 1:50



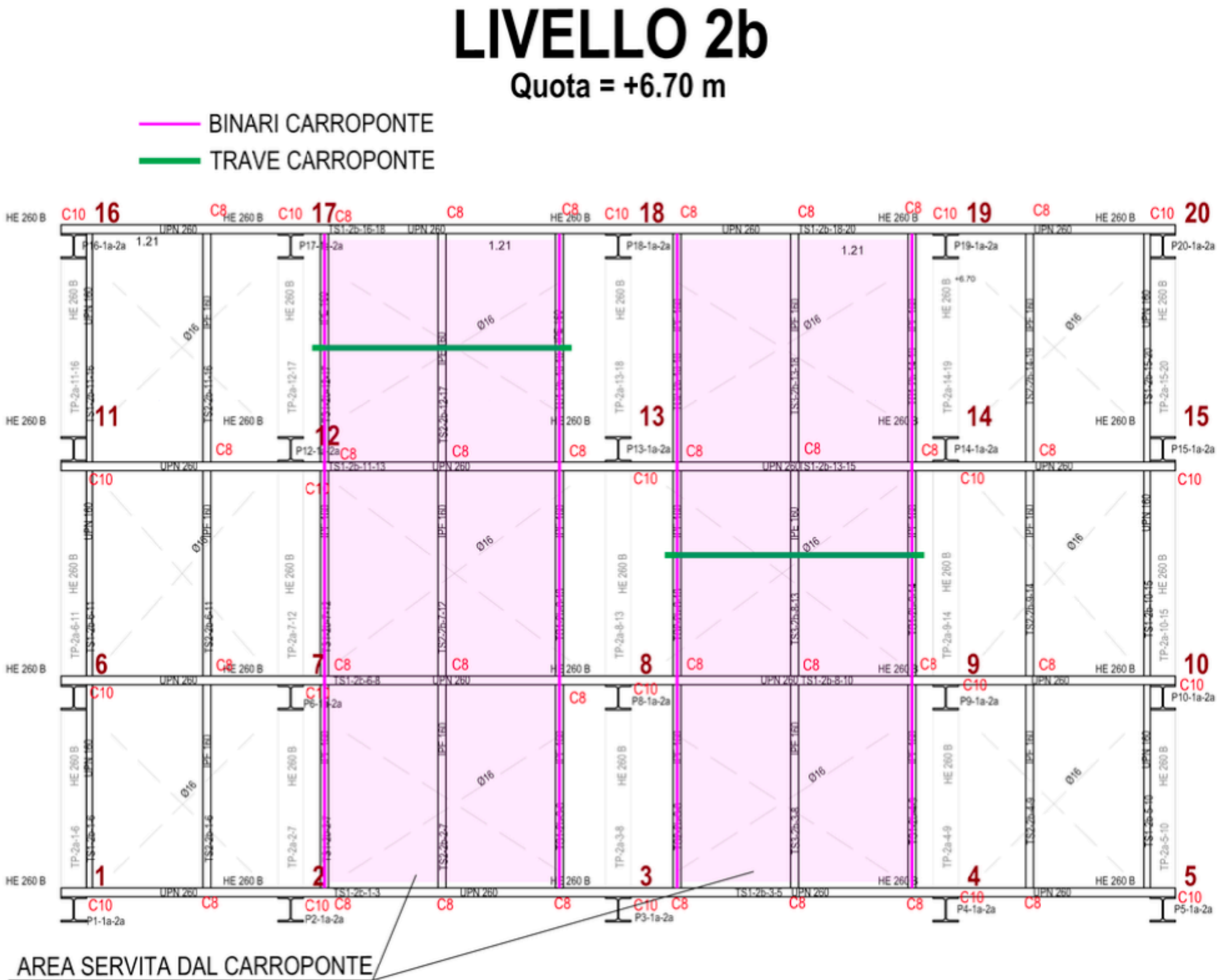
LEGENDA	
Quadro elettrico (linea Normale) con indicazione della zona controllata	
Quadro elettrico (linea UPS) con indicazione della zona controllata	
Indicatore zona di competenza quadro	
Presa a spina a poli allineati con alveoli schermati tipo tedesca - linea Normale	
Presa a spina a poli allineati con alveoli schermati tipo tedesca - linea UPS	
Presa trifase CEE 16A 3P+N+PE	
Presa trifase CEE 16A 3P+N+PE	



ISTITUTO NAZIONALE DI FISICA NUCLEARE LABORATORI NAZIONALI DEL GRAN SASSO SERVIZIO STRUTTURA SOTTERRANEA E PROGETTI SPECIALI	
CIG 96555235A4 CUP I19D22000090007	LAVORI DI REALIZZAZIONE DI UNA STRUTTURA IN CARPENTERIA METALLICA PNRR LNGS FUTURE - CRYO-P
VARIANTE IMPIANTO ELETTRICO	
N° ELABORATO IMP.03	ELABORATO Impianti SCHEMA RETE ELETTRICA Pianta Piano Terra
R.U.P. Ing. Paolo Martella	PROGETTAZIONE IMPRESA ESECUTRICE SAGGESE S.p.A. Via P. D'Aragorio, 32 84014 - Roccaraso Inferiore (SA) C.F. e P.IVA: 03630400632
SCALA 1:50	UFFICIO DI DIREZIONE DEI LAVORI
N. PAG. -	Direttore dei Lavori Ing. Umberto Di Sabatino
REV. -	Direttore Operativo Impianti Elettrici Per.Ind. Nicola Massimiani
DATA MARZO 2025	Direttore Operativo Impianti Speciali Ing. Paolo Cavalcante

Cryo-P utilities: crane

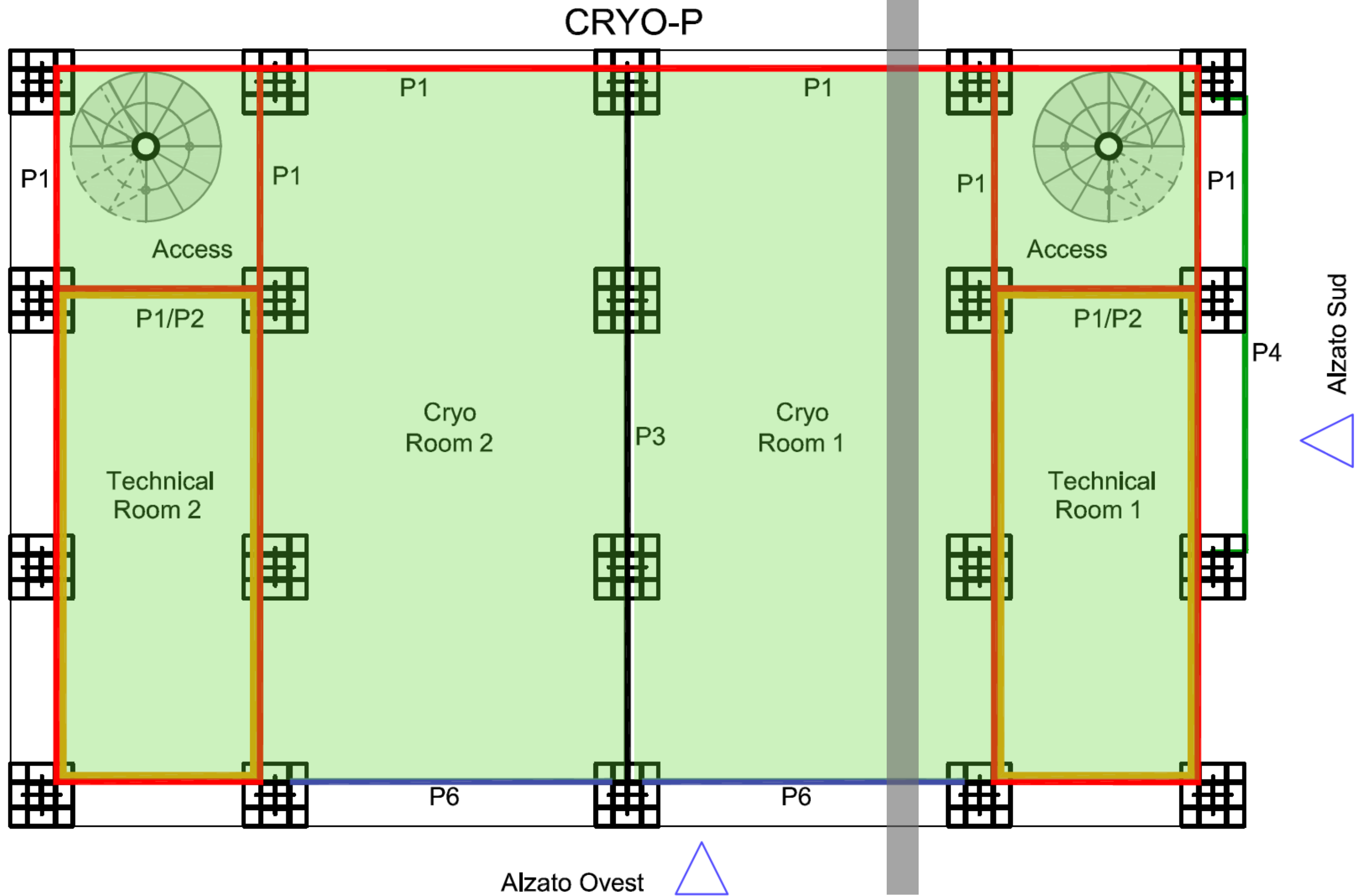
mechanical components, ecc.



Cryo-P utilities: ground experimental area

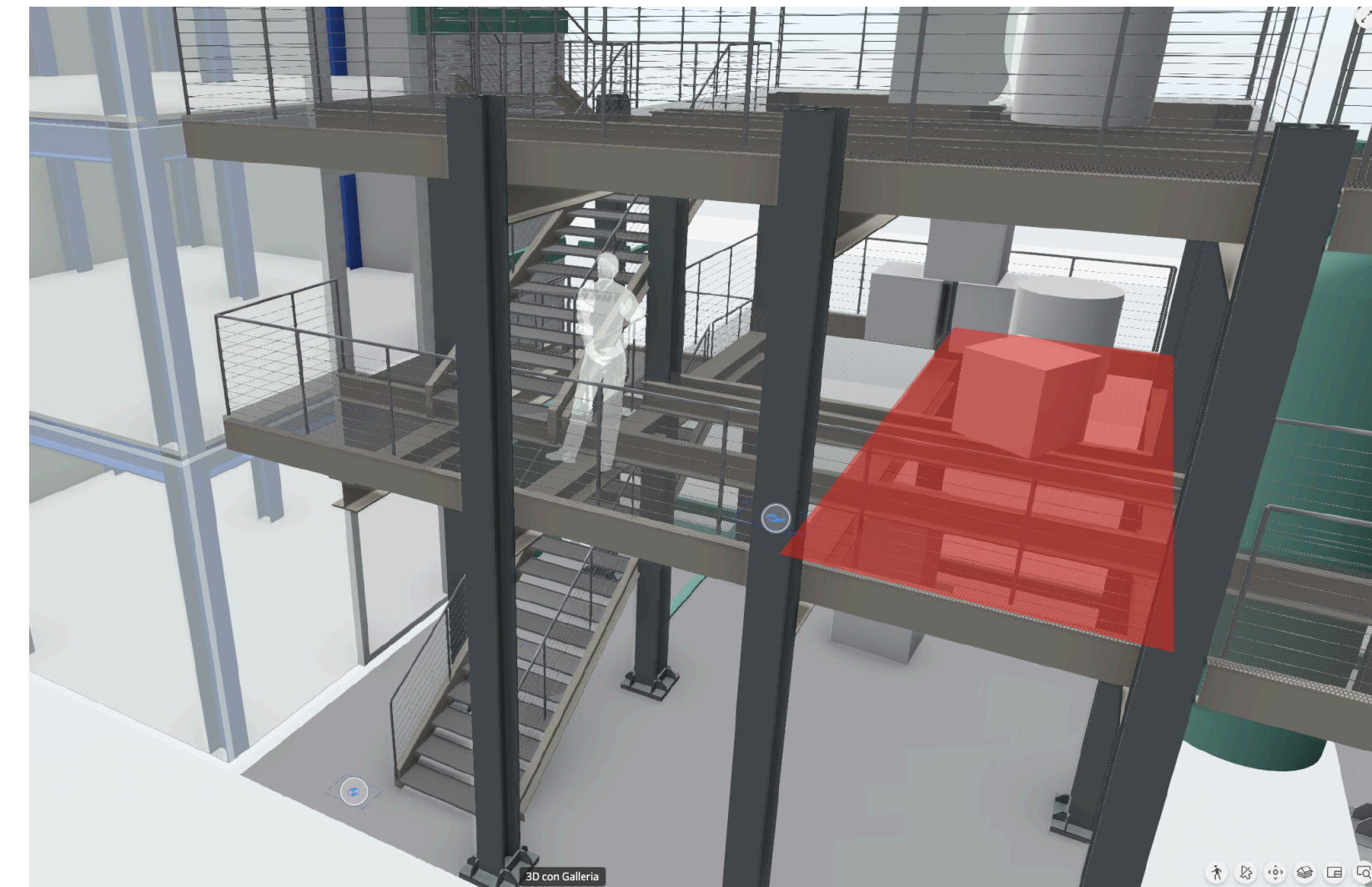
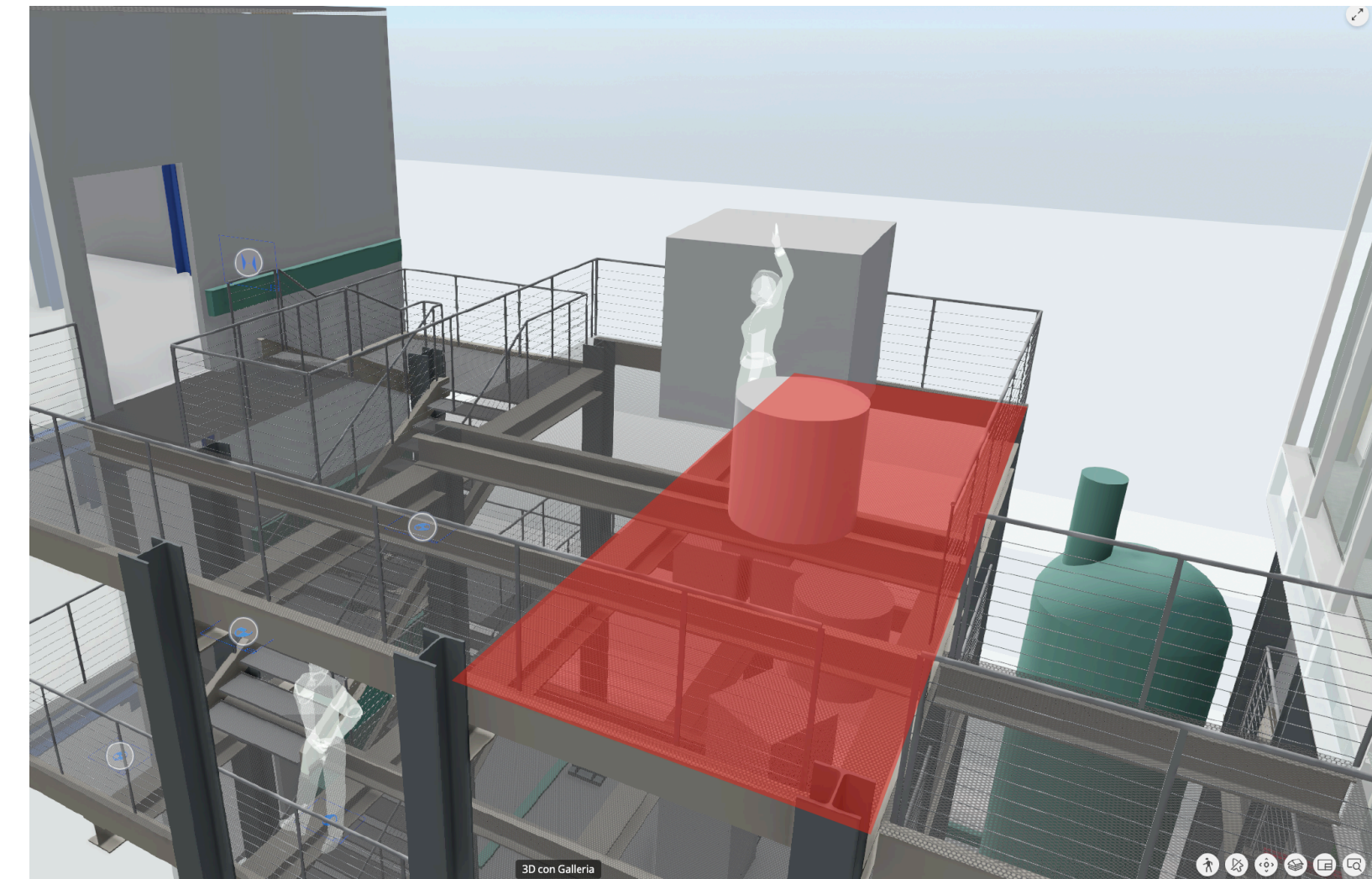
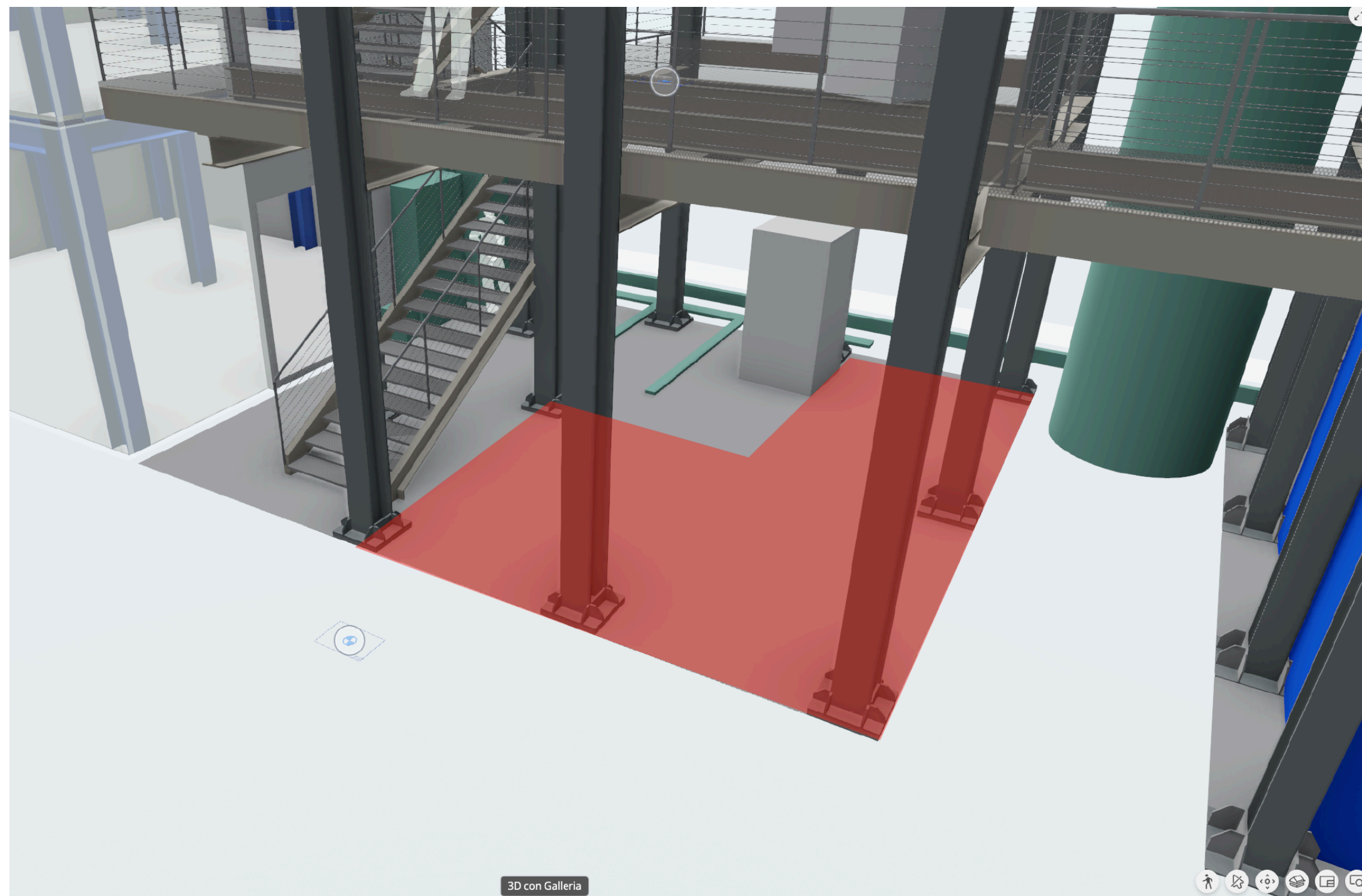
- Definition of levelling and resin coating of the walking surface at ground floor

LEGENDA		
	P1	Pannello Sandwich Lana Roccia 5 cm
	P2	Pannello Sandwich Lana Roccia Insonorizzato 5 cm
	P3	Pannello Sandwich in lana di roccia con Lamiera Microforata 5 cm
	P4	Parete Intelaiata Aggettante Lamiera Microforata
	P5	Parete intelaiata in vetro con telaio in alluminio - interna -
	P6	Parete intelaiata in vetro con telaio in alluminio - esterna -
	P7	Parete Intelaiata Aggettante Vetrata Vetro Trasparente/Translucido
		Tamponature e Divisori
		Tamponature e Divisori
		Divisori
		Tamponature
		Divisori
		Tamponature
		Tamponature

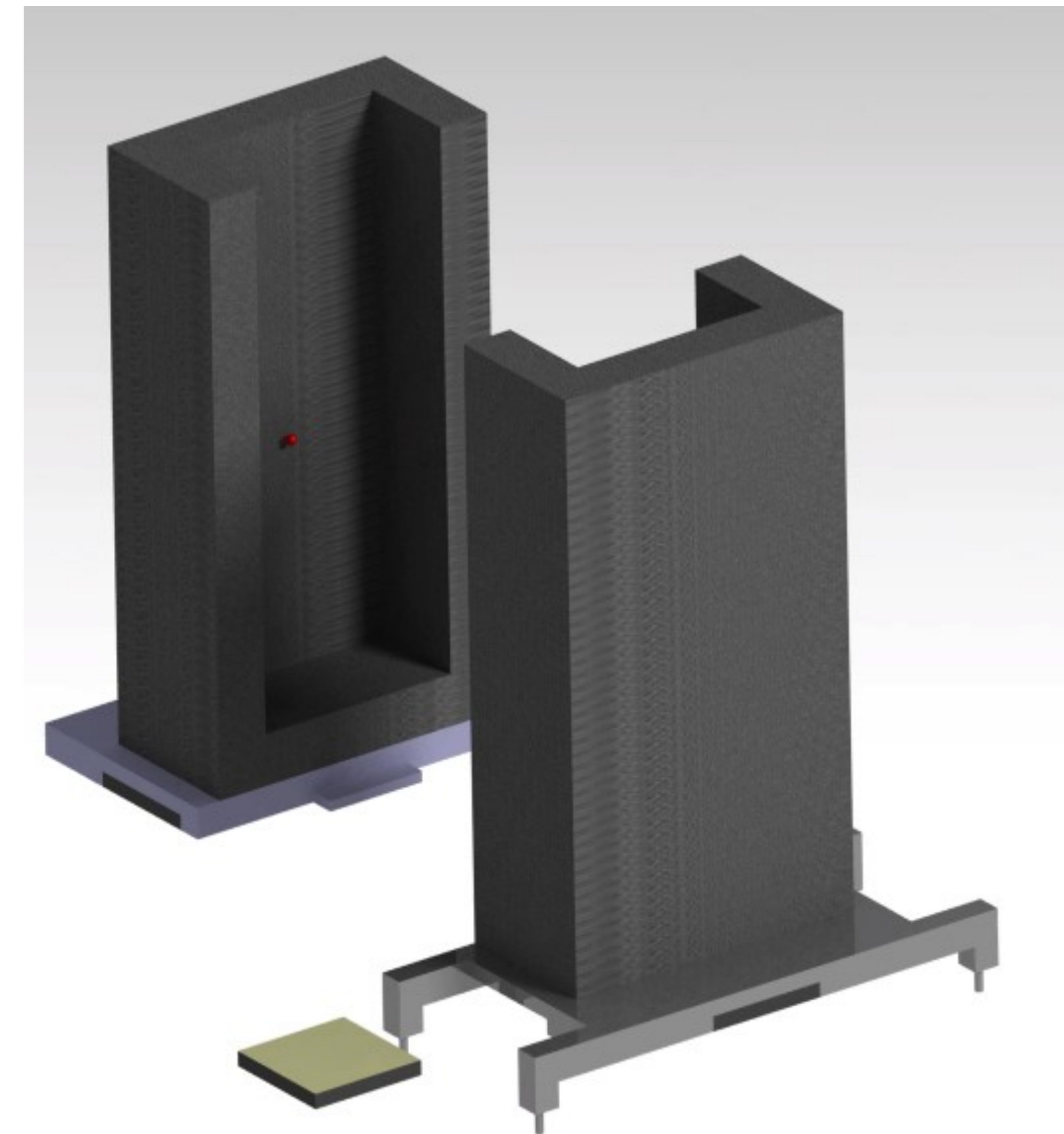
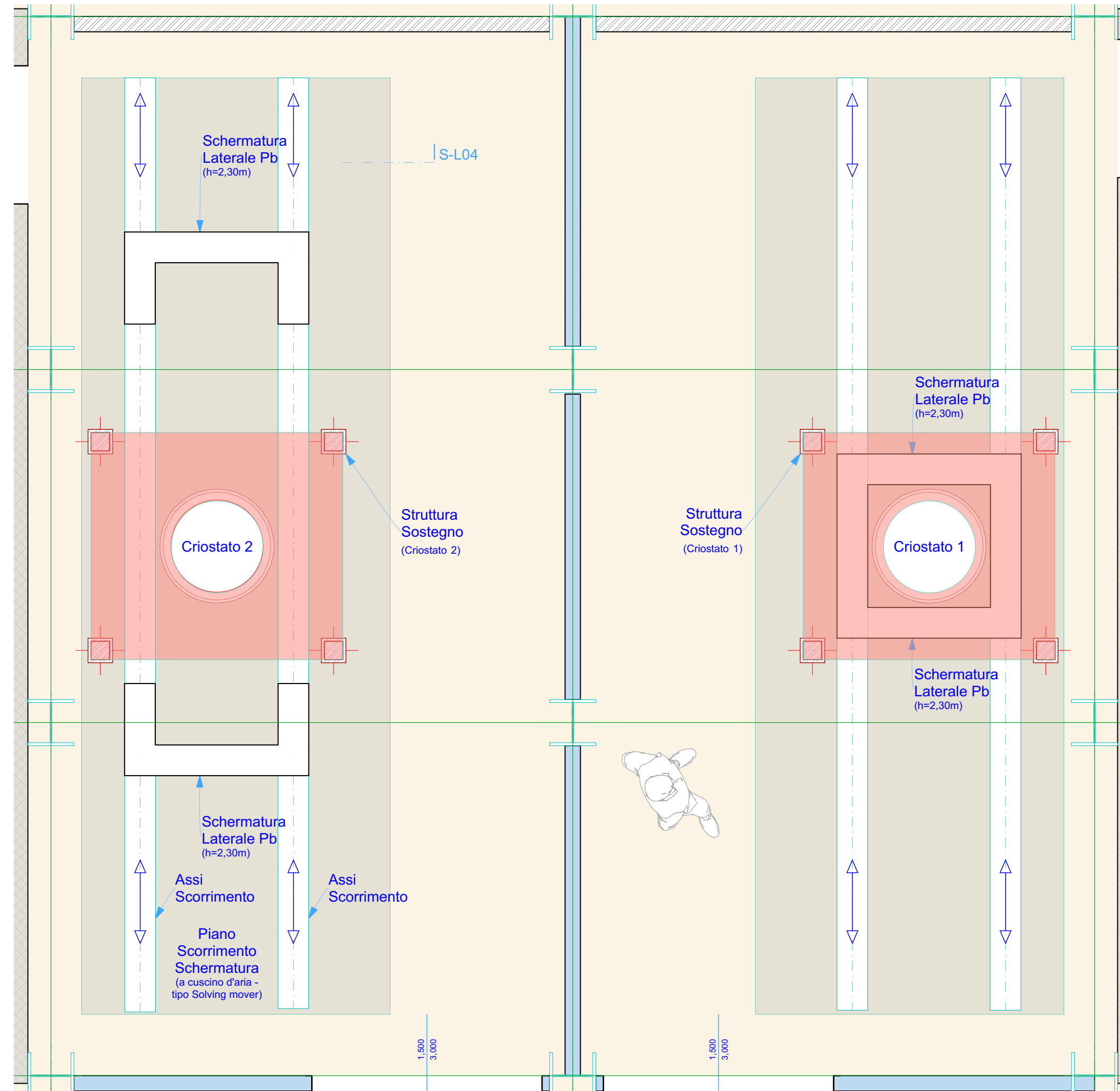


Cryo-P utilities: others

- Discussions have started for:
 - water cooling system
 - technical gas distribution system
 - ventilation and fancoil system

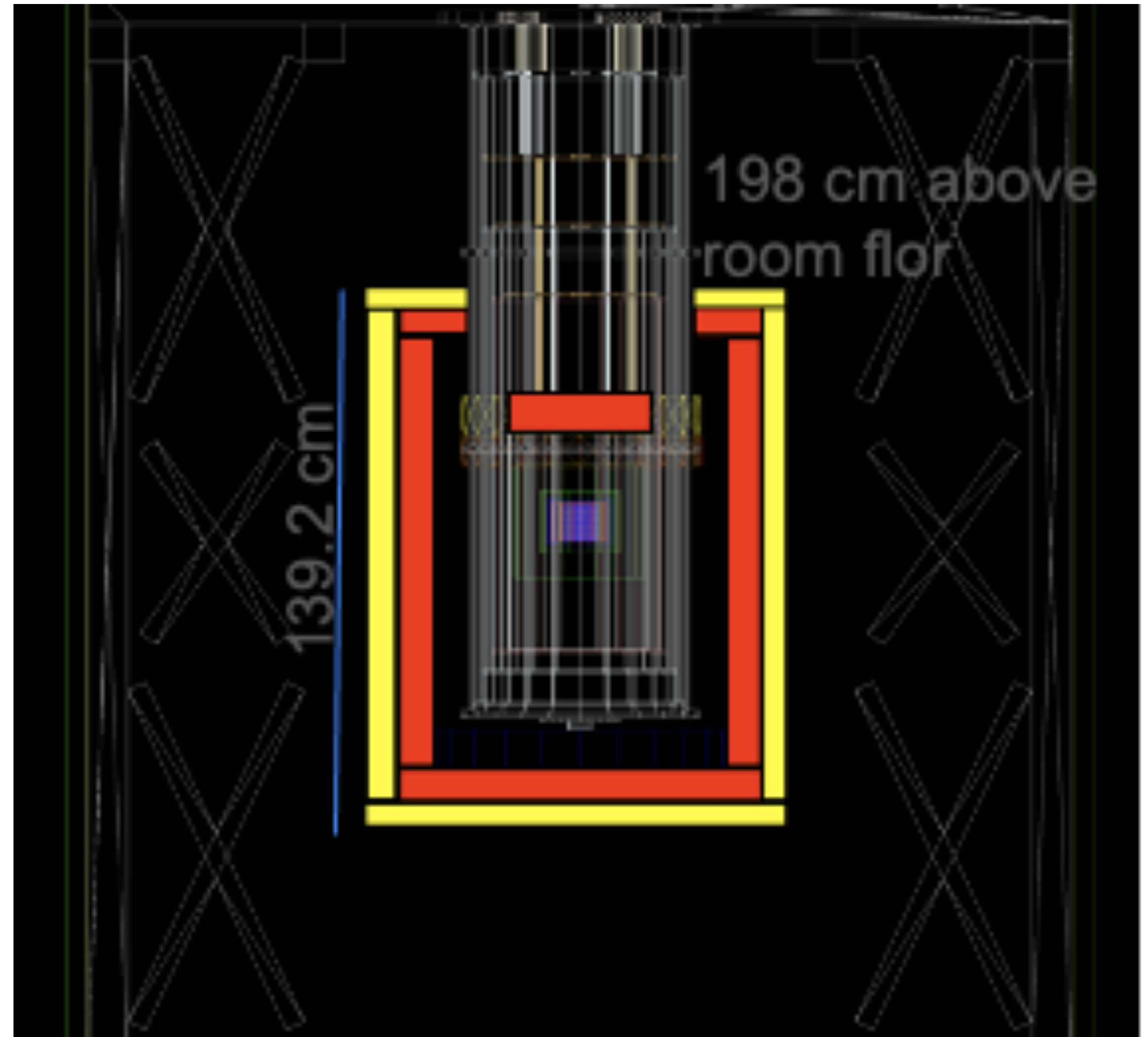


Sliding side lead shields: conceptual

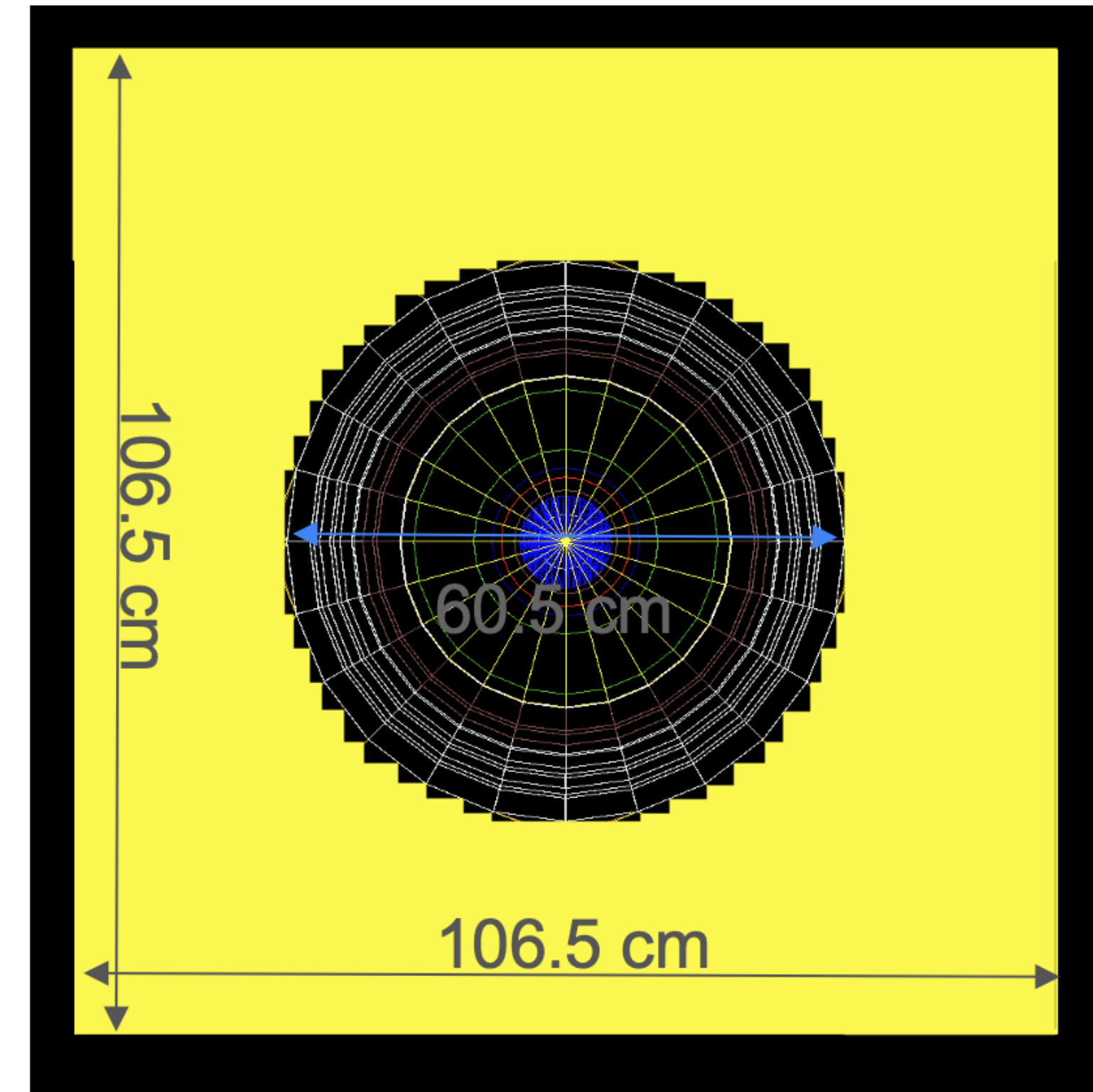
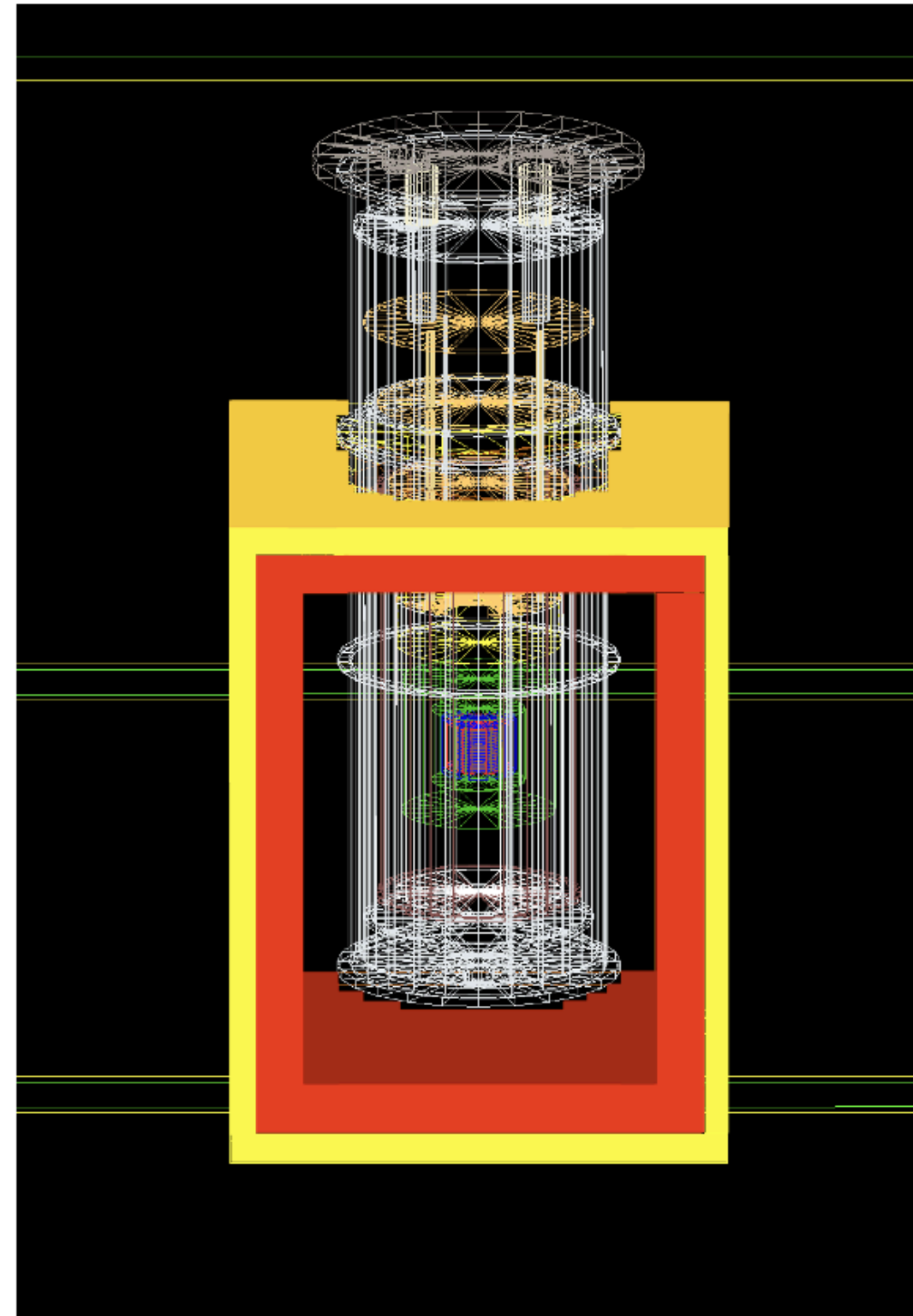
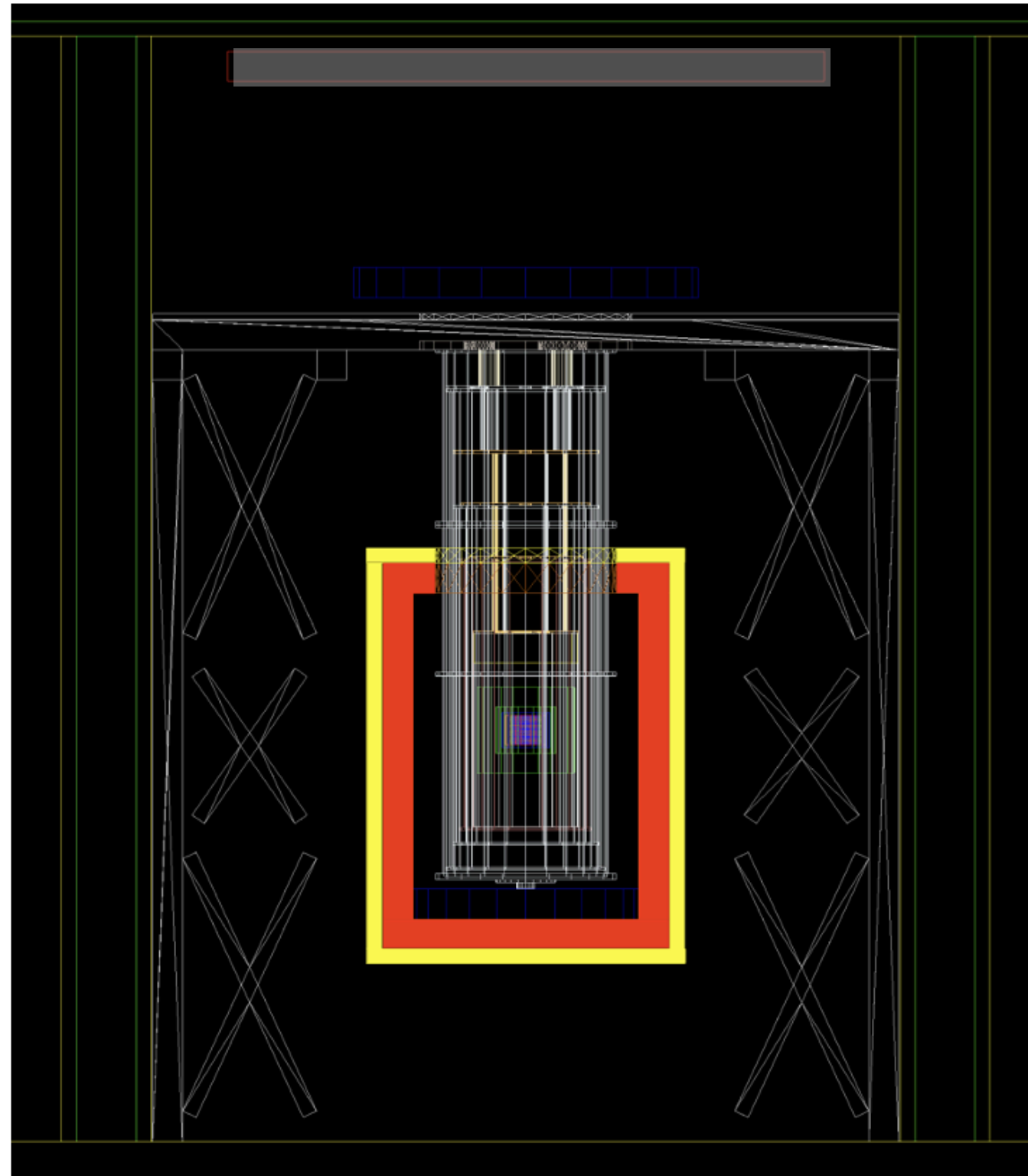


Sliding side lead shields: best case

- Simulations performed by UNAM group
- Hp:
 - Pb activity set at OPERA Pb activities upper limits
 - Cu purity not considered
- Baseline (best case):
10 cm Cu + 5 cm Pb
 - Cu mass: 4.72 T
 - Pb mass: 4.07 T
- Alternative:
5 cm Cu + 10 cm Pb
 - Cu mass: 2.11 T
 - Pb mass: 7.41 T



Sliding side lead shields: conclusions



- Adding a hat shielding does reduce the background
- Most of the background comes from the empty spaces above BULLKID (inside the cryostat)
 - Lead thickness $>6\text{cm}$ does not impact significantly the background
 - Top lead shielding with the current geometry does not impact significantly the background

Radiopurity of GSO (preliminary)

- Small GSO ($\text{Gd}_3\text{O}_5\text{Si}$) sample: volume $1.7 \times 1 \times 1 \text{ cm}^3$, mass $\sim 12\text{g}$
- Preparation of the GSO sample (solubilisation):
 - sample dissolved in phosphoric acid (ortho-phosphoric acid H_3PO_4)
 - etch with hydrofluoric acid and subsequent evaporation to eliminate the silicon present in the crystal (ok)
 - addition of nitric acid/hydrochloric acid mixture to dissolve the GSO without silicon (not ok)
- Measurements were performed with HR-ICP-MS Th and U in medium resolution and K in high resolution
- Results:

^{238}U	550 - 165 ppb
^{232}Th	< 200 ppb
^{39}K	10 - 5 ppm

Thanks

